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2828
Dkt. 2271/60102
#9/Amend a
Done
7/16/02

Application of : Takashi TAKAHASHI
Serial No. : 09/408,437
Date Filed : September 29, 1999
For : SEMICONDUCTOR DEVICE WITH SATURABLE ABSORBING LAYER
Group Art Unit: 2828
Examiner: A. Rodriguez

Assistant Commissioner for Patents
Washington, D.C. 20231

1185 Avenue of the Americas
New York, N.Y. 10036

Sir: AMENDMENT

In response to the Office Action dated March 28, 2002, please amend the above-identified application as follows:

In the Claims:

Please amend claims 1, 6, 13 and 18 as follows:

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Sub C7

1. (Amended)
- A semiconductor device comprising:
a semiconductor substrate of a first conductivity type;
a first cladding layer of said first conductivity type formed on said semiconductor substrate;

AI

I hereby certify that this paper is being deposited this date with the U.S. Postal Service as first class mail addressed to the Assistant Commissioner for Patents, Washington, D.C. 20231.
Richard F. Jaworski
Reg. No. 33,515
June 27, 2002
Date